

# HN462732, HN462732G, HN462732P

## 4096-word $\times$ 8-bit U.V. Erasable and Programmable Read Only Memory

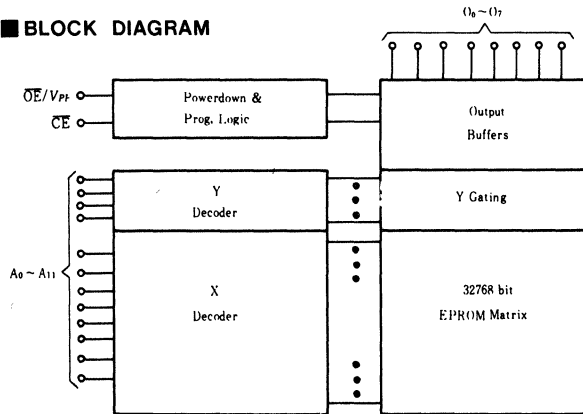
The HN462732 is a 4096 word by 8 bit erasable and electrically programmable ROM. This device is packaged in a 24-pin, dual-in-line package with transparent lid. The transparent lid allows the user to expose the chip to ultraviolet light to erase the bit pattern, whereby a new pattern can then be written into the device.

The HN462532P is a 4096 word by 8 bit, one time programmable ROM. This device is packaged in a 24-pin, dual-in-line plastic package.

### ■ FEATURES

- Single Power Supply . . . . . +5V  $\pm$ 5%
- Simple Programming . . . . . Program Voltage: +25V D.C.  
Program with One 50ms Pulse
- Static . . . . . No Clocks Required
- Inputs and Outputs TTL Compatible During Both Read and Program Modes
- Fully Decoded On-Chip Address Decode
- Access Time . . . . . 450ns (max)
- Low Power Dissipation . . . . 150mA (max) Active Currents  
30mA (max) Standby Current
- Three State Output . . . . . OR-Tie-Capability
- Compatible with INTEL 2732

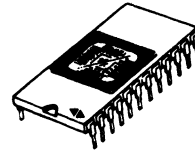
### ■ BLOCK DIAGRAM



### ■ MODE SELECTION

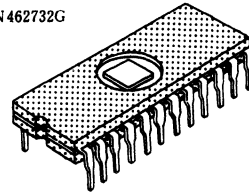
Mode	Pins	$\overline{CE}$ (18)	$\overline{OE}/V_{PP}$ (20)	$V_{CC}$ (24)	Outputs (9~11, 13~17)
Read		$V_{IL}$	$V_{IL}$	+5	Dout
Stand by		$V_{IH}$	Don't Care	+5	High Z
Program		$V_{IL}$	$V_{PP}$	+5	Din
Program Verify		$V_{IL}$	$V_{IL}$	+5	Dout
Program Inhibit		$V_{IH}$	$V_{PP}$	+5	High Z

HN 462732



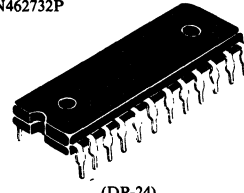
(DC-24C)

HN 462732G



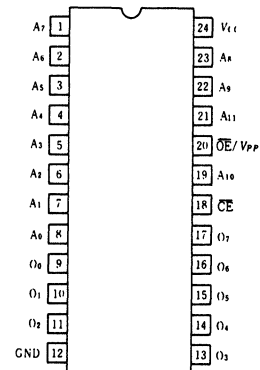
(DG-24B)

HN462732P



(DP-24)

### ■ PIN ARRANGEMENT



(Top View)

## ■ ABSOLUTE MAXIMUM RATINGS

Item	Symbol	Value*	Unit
Operating Temperature Range	$T_{opr}$	0 to +70	°C
Storage Temperature Range	$T_{stg}$	-65 to +125	°C
All Input and Output Voltage*	$V_T$	-0.3 to +7	V
$V_{PP}$ Voltage*	$\overline{OE}/V_{PP}$	-0.3 to +28	V

\* With respect to GND

## ■ READ OPERATION

### ● DC AND OPERATING CHARACTERISTICS ( $T_a=0$ to +70°C, $V_{CC}=5V \pm 5\%$ , $V_{PP}=V_{CC} \pm 0.6V$ )

Parameter	Symbol	Test Condition	min.	typ.	max.	Unit
Input Leakage Current (Except $\overline{OE}/V_{PP}$ )	$I_{LI1}$	$V_{IN}=5.25V$	—	—	10	$\mu A$
$\overline{OE}/V_{PP}$ Input Leakage Current	$I_{LI2}$	$V_{IN}=5.25V$	—	—	10	$\mu A$
Output Leakage Current	$I_{LO}$	$V_{out}=5.25V$	—	—	10	$\mu A$
$V_{CC}$ Current (Standby)	$I_{CC1}$	$\overline{CE}=V_{IH}$ , $\overline{OE}=V_{IL}$	—	—	30	mA
$V_{CC}$ Current (Active)	$I_{CC2}$	$\overline{OE}=\overline{CE}=V_{IL}$	—	—	150	mA
Input Low Voltage	$V_{IL}$		-0.1	—	0.8	V
Input High Voltage	$V_{IH}$		2.0	—	$V_{CC}+1$	V
Output Low Voltage	$V_{OL}$	$I_{OL}=2.1mA$	—	—	0.45	V
Output High Voltage	$V_{OH}$	$I_{OH}=-400\mu A$	2.4	—	—	V

### ● AC CHARACTERISTICS ( $T_a=0$ to +70°C, $V_{CC}=5V \pm 5\%$ , $V_{PP}=V_{CC} \pm 0.6V$ )

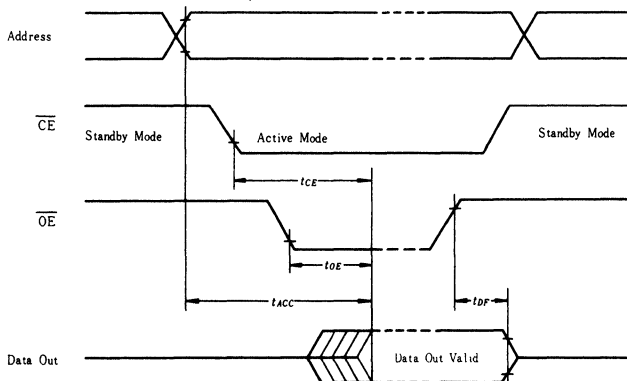
Parameter	Symbol	Test Condition	min	typ	max	Unit
Address to Output Delay	$t_{ACC}$	$\overline{CE}=\overline{OE}=V_{IL}$	—	—	450	ns
$\overline{CE}$ to Output Delay	$t_{CE}$	$\overline{OE}=V_{IL}$	—	—	450	ns
Output Enable to Output Delay	$t_{OE}$	$\overline{CE}=V_{IL}$	—	—	120	ns
Output Enable High to Output Float *	$t_{DF}$	$\overline{CE}=V_{IL}$	0	—	100	ns
Address to Output Hold	$t_{OH}$	$\overline{CE}=\overline{OE}=V_{IL}$	0	—	—	ns

\*  $t_{DF}$  defines the time at which the output achieves the open circuit condition and is not referenced to output voltage levels.

## ● SWITCHING CHARACTERISTICS

### Test Condition

Input Pulse Levels: 0.8V to 2.2V  
 Input Rise and Fall Times:  $\leq 20ns$   
 Output Load: 1TTL Gate + 100pF  
 Reference Level for Measuring Timing: Inputs 1V and 2V  
 Outputs 0.8V and 2V



### ● CAPACITANCE ( $T_a=25^\circ C$ , $f=1MHz$ )

Parameter	Symbol	Test Condition	min.	typ.	max.	Unit
Input Capacitance (Except $\overline{OE}/V_{PP}$ )	$C_{IN1}$	$V_{IN}=0V$	—	—	6	pF
$\overline{OE}/V_{PP}$ Input Capacitance	$C_{IN2}$	$V_{IN}=0V$	—	—	20	pF
Output Capacitance	$C_{out}$	$V_{out}=0V$	—	—	12	pF

## PROGRAMMING OPERATION

### DC PROGRAMMING CHARACTERISTICS ( $V_{CC}=5V \pm 5\%$ , $V_{PP}=25V \pm 1V$ , $T_a=25^\circ\text{C} \pm 5^\circ\text{C}$ )

Parameter	Symbol	Test Condition	min.	typ.	max.	Unit
Input Leakage Current	$I_{LI}$	$V_{IN}=5.25V/0.4V$	—	—	10	$\mu\text{A}$
Output Low Voltage During Verify	$V_{OL}$	$I_{OL}=2.1\text{mA}$	—	—	0.4	V
Output High Voltage During Verify	$V_{OH}$	$I_{OH}=-400\mu\text{A}$	2.4	—	—	V
$V_{CC}$ Supply Current	$I_{CC}$		—	—	150	mA
Input Low Level	$V_{IL}$		-0.1	—	0.8	V
Input High Level (All Input Except $\overline{OE}/V_{PP}$ )	$V_{IH}$		2.0	—	$V_{CC}+1$	V
$V_{PP}$ Supply Current	$I_{PP}$	$\overline{CE}=V_{IL}$ , $\overline{OE}=V_{PP}$	—	—	30	mA

### AC PROGRAMMING CHARACTERISTICS ( $V_{CC}=5V \pm 5\%$ , $V_{PP}=25V \pm 1V$ , $T_a=25^\circ\text{C} \pm 5^\circ\text{C}$ )

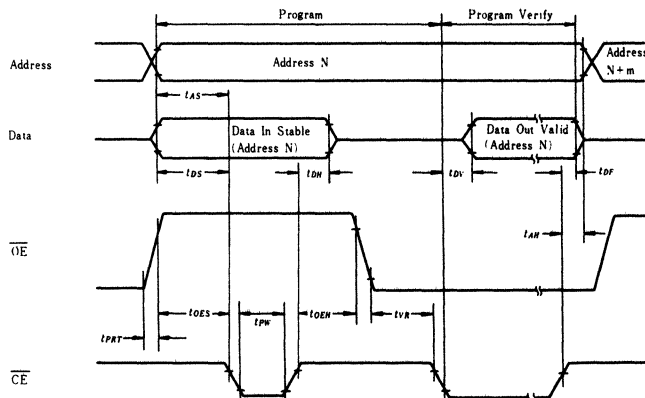
Parameter	Symbol	Test Condition	min.	typ.	max.	Unit
Address Setup Time	$t_{AS}$		2	—	—	$\mu\text{s}$
$\overline{OE}$ Setup Time	$t_{OES}$		2	—	—	$\mu\text{s}$
Data Setup Time	$t_{DS}$		2	—	—	$\mu\text{s}$
Address Hold Time	$t_{AH}$		0	—	—	$\mu\text{s}$
$\overline{OE}$ Hold Time	$t_{OEH}$		2	—	—	$\mu\text{s}$
Data Hold Time	$t_{DH}$		2	—	—	$\mu\text{s}$
Chip Enable to Output Float Delay*	$t_{DF}$		0	—	120	ns
Data Valid from $\overline{CE}$	$t_{DV}$	$\overline{CE}=V_{IL}$ , $\overline{OE}=V_{IL}$	—	—	1	$\mu\text{s}$
$\overline{CE}$ Pulse Width During Programming	$t_{PW}$		45	50	55	ms
$\overline{OE}$ Pulse Rise Time During Programming	$t_{PRT}$		50	—	—	ns
$V_{PP}$ Recovery Time	$t_{VR}$		2	—	—	$\mu\text{s}$

\*  $t_{DF}$  defines the time at which the output achieves the open circuit condition and is not referenced to output voltage levels.

### SWITCHING CHARACTERISTICS

#### Test Conditions

Input Pulse Level: 0.8V to 2.2V  
 Input Rise and Fall Times:  $\leq 20\text{ns}$   
 Output Load: 1TTL Gate + 100pF  
 Reference Level for Measuring Timing: Inputs; 1V and 2V, Outputs; 0.8V and 2V



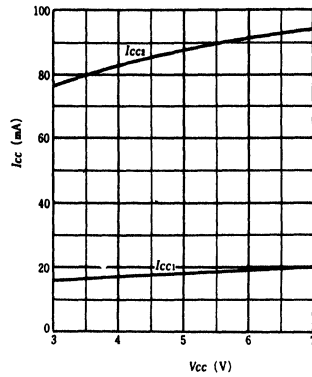
### ERASE

Erasure of HN462732 is performed by exposure to Ultra-violet light of 2537Å, and all the output data are changed to "1" after this procedure.

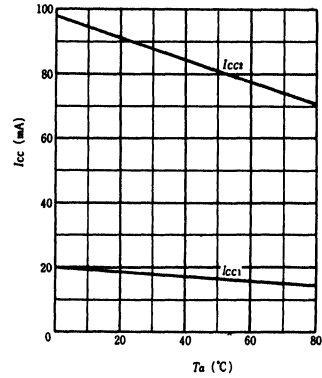
The minimum integrated dose (i.e., UV intensity x exposure time) for erasure is  $15W \cdot \text{sec}/\text{cm}^2$ .

**NOTE THAT THE HN462743P CANNOT BE ERASED.**

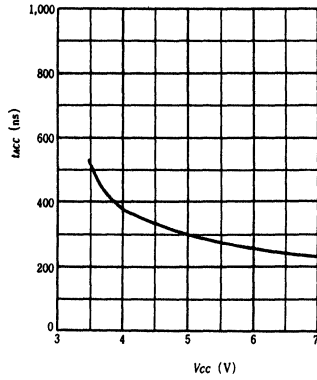
**SUPPLY CURRENT vs. SUPPLY VOLTAGE**



**SUPPLY CURRENT vs. AMBIENT TEMPERATURE**



**ACCESS TIME vs. SUPPLY VOLTAGE**



**ACCESS TIME vs. AMBIENT TEMPERATURE**

